

## **NCE N-Channel Super Trench III Power MOSFET**

#### **Description**

The series of devices uses **Super Trench III** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of  $R_{\text{DS(ON)}}$  and  $Q_g$ . This device is ideal for high-frequency switching and synchronous rectification.

#### **Application**

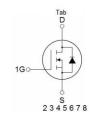
- DC/DC Converter
- •Ideal for high-frequency switching and synchronous rectification

#### **General Features**

- Excellent gate charge x R<sub>DS(on)</sub> product(FOM)
- Very low on-resistance RDS(on)
- 175 °C operating temperature
- Pb-free lead plating

100% UIS TESTED! 100% ΔVds TESTED!





**Schematic Diagram** 

#### **Package Marking and Ordering Information**

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCEP040NH150LL	NCEP040NH150LL	TOLL	-	-	-

#### Absolute Maximum Ratings (T<sub>C</sub>=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	VDS	150	V
Gate-Source Voltage	V <sub>G</sub> s	±20	V
Drain Current-Continuous	I <sub>D</sub>	265	Α
Drain Current-Continuous(T <sub>C</sub> =100 ℃)	I <sub>D</sub> (100°C)	186	Α
Pulsed Drain Current	I <sub>DM</sub>	1060	А
Maximum Power Dissipation	P <sub>D</sub>	618	W
Derating factor		4.0	W/℃
Single pulse avalanche energy (Note 1)	Eas	1697	mJ
Operating Junction and Storage Temperature Range	$T_{J}, T_{STG}$	-55 To 175	$^{\circ}$ C

#### **Thermal Characteristic**

Thermal Resistance,Junction-to-Case	R <sub>θJC</sub>	0.25	°C/W
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# NCEP040NH150LL

# Electrical Characteristics (T<sub>C</sub>=25 ℃ unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250μA	150	-	-	V
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =150V,V <sub>GS</sub> =0V	-	-	1	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V	-	-	±100	nA
On Characteristics						
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS}$ , $I_D=250\mu A$	2.5	3.3	4.5	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =20A	-	3.3	4.0	mΩ
Forward Transconductance	<b>g</b> FS	V <sub>DS</sub> =10V,I <sub>D</sub> =40A	-	75	-	S
Dynamic Characteristics						
Input Capacitance	Clss	V <sub>DS</sub> =75V,V <sub>GS</sub> =0V,	-	7150	-	PF
Output Capacitance	Coss		-	2050	-	PF
Reverse Transfer Capacitance	C <sub>rss</sub>	F=1.0MHz		47	-	PF
Switching Characteristics (Note 2)						
Turn-on Delay Time	t <sub>d(on)</sub>		-	30	-	nS
Turn-on Rise Time	tr	$V_{DD}$ =75 $V$ , $I_{D}$ =75 $A$	-	40	-	nS
Turn-Off Delay Time	t <sub>d(off)</sub>	V <sub>GS</sub> =10V,R <sub>G</sub> =4.7Ω	-	70	-	nS
Turn-Off Fall Time	t <sub>f</sub>		-	15	-	nS
Total Gate Charge	Qg	V <sub>DS</sub> =75V,I <sub>D</sub> =20A,	-	106	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	36	-	nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V	-	27	-	nC
Drain-Source Diode Characteristics						
Diode Forward Voltage	V <sub>SD</sub>	V <sub>GS</sub> =0V,I <sub>F</sub> =20A	-	-	1.2	V
Diode Forward Current	Is		-	-	265	Α
Reverse Recovery Time	t <sub>rr</sub>	T <sub>J</sub> = 25°C, I <sub>F</sub> = 100A	-	108	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/μs	-	270	-	nC

#### Notes:

<sup>1.</sup> EAS condition : Tj=25  $^{\circ}\text{C}$  ,V\_DD=50V,V\_G=10V,L=0.5mH,Rg=25 $\Omega$ 

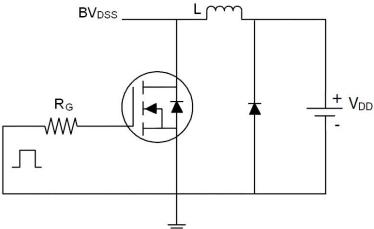
<sup>2.</sup> Guaranteed by design, not subject to production

<sup>3.</sup> These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of TJ(MAX)=175°C. The SOA curve provides a single pulse rating.

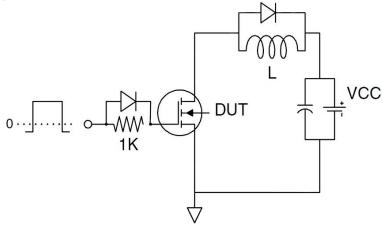


#### **Test Circuit**

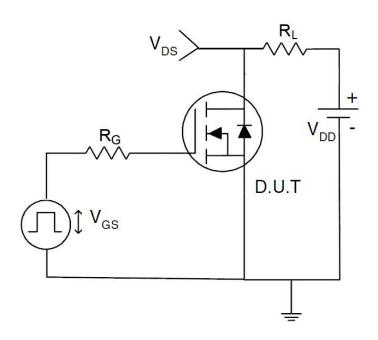
## 1) E<sub>AS</sub> test Circuit



## 2) Gate charge test Circuit

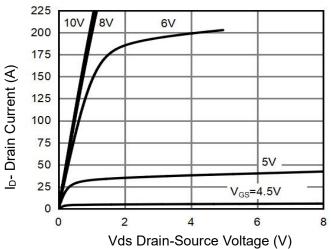


#### 3) Switch Time Test Circuit

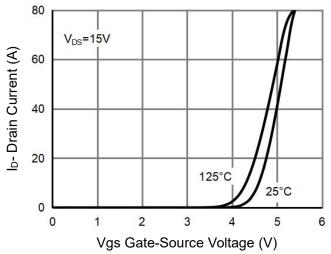




#### **Typical Electrical and Thermal Characteristics**



**Figure 1 Output Characteristics** 



**Figure 2 Transfer Characteristics** 

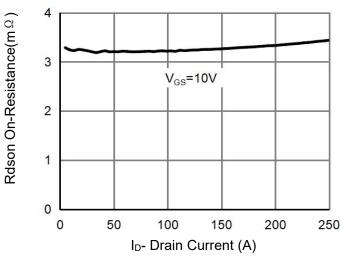


Figure 3 Rdson- Drain Current

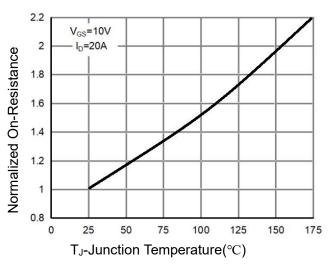


Figure 4 Rdson-JunctionTemperature

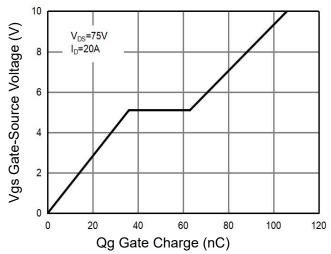


Figure 5 Gate Charge

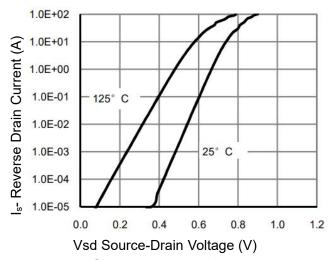


Figure 6 Source- Drain Diode Forward



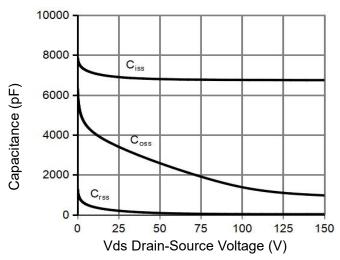
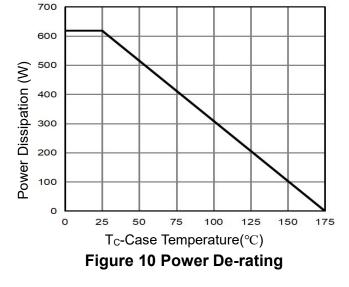


Figure 7 Capacitance vs Vds



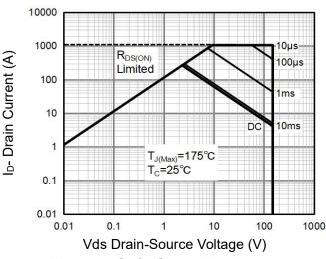


Figure 8 Safe Operation Area (Note3)

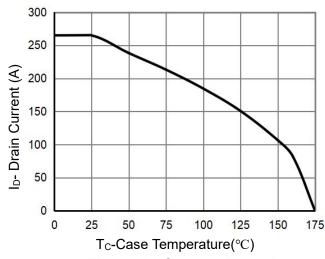


Figure 11 Current De-rating

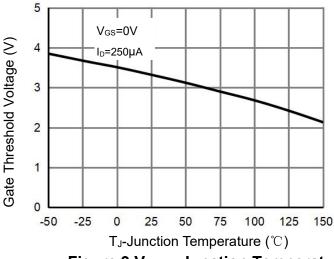


Figure 9 V<sub>GS(th)</sub>-Junction Temperature

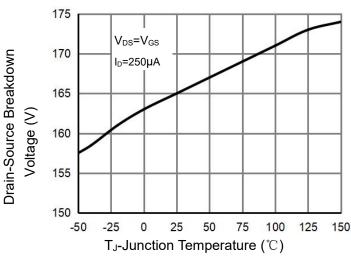
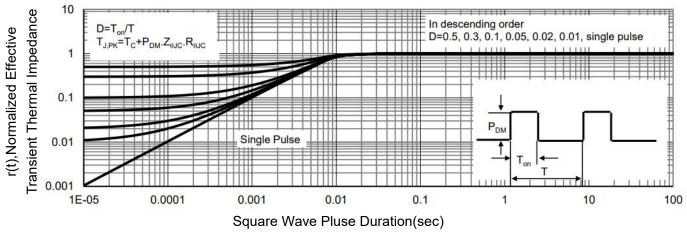


Figure 12 BV<sub>DSS</sub>-Junction Temperature

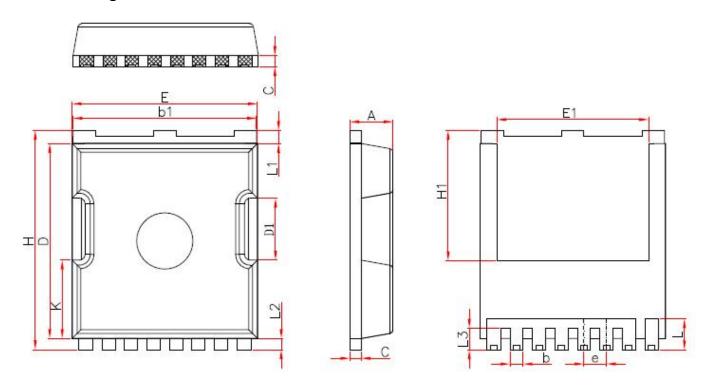




**Figure 13 Normalized Maximum Transient Thermal Impedance** 



# **TOLL Package Information**



Symbol	Millimeters		
V660	Min.	Nom.	Max.
A	2.20	2.30	2.40
b	0.65	0.75	0.85
b1	9.70	9.80	9.90
С	0.50	0.60	0.70
D	10.30	10.40	10.50
D1	3.15	3.3	3.45
Е	9.70	9.90	10.10
E1	8.00	8.10	8. 20
е	1.10	1.20	1.30
Н	11.6	11.7	11.8
H1	6.85	6.95	7.05
K	4.08	4.18	4.28
L	1.60	1.65	2.10
L1	0.60	0.70	0.80
L2	0.50	0.60	0.70
L3	1.05	1.20	1.30



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# NCEP040NH150LL

#### **Revision History**

Revision	Date	Subjects
V1.0	2023.11.02	Product data sheet
V2.0	2024.03.05	Update Current De-rating R <sub>DS(ON)</sub> Typ Value

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